

IXFH66N20Q Information


For Reference Only

Part Number [IXFH66N20Q](#)
Manufacturer IXYS
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 200V 66A TO-247
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


IXFH66N20Q Specifications

Manufacturer Part Number	IXFH66N20Q
Manufacturer	IXYS
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	HiPerFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (V _{ds})	200V
Current - Continuous Drain (I _d) @ 25°C	66A (T _c)
Drive Voltage (Max R _{ds} On, Min R _{ds} On)	10V
V _{gs} (th) (Max) @ I _d	4V @ 4mA
Gate Charge (Q _g) (Max) @ V _{gs}	105nC @ 10V
Input Capacitance (C _{iss}) (Max) @ V _{ds}	3700pF @ 25V
V _{gs} (Max)	±30V
FET Feature	-
Power Dissipation (Max)	400W (T _c)
R _{ds} On (Max) @ I _d , V _{gs}	40 mOhm @ 33A, 10V
Operating Temperature	-55°C ~ 150°C (T _J)
Mounting Type	Through Hole
Supplier Device Package	TO-247AD (IXFH)
Package / Case	TO-247-3

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IXFH66N20Q Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFH66N20Q Payment Methods



IXFH66N20Q Shipping Methods



If you have any question about IXFH66N20Q, please do not hesitate to contact us!

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